

Features

- High Slew Rate30V/ μ s
- Fast Settling330ns
- Wide Power Bandwidth500KHz
- High Gain Bandwidth12MHz
- High Input Impedance50M Ω
- Low Offset Current10nA
- Internally Compensated For Unity Gain Stability

Description

HA-2500/2502/2505 comprises a series of monolithic operational amplifiers whose designs are optimized to deliver excellent slew rate, bandwidth, and settling time specifications. The outstanding dynamic features of this internally compensated device are complemented with low offset voltage and offset current.

These dielectrically isolated amplifiers are ideally suited for applications such as data acquisition, R.F., video, and pulse conditioning circuits. Slew rates of $\pm 25\text{V}/\mu\text{s}$ and 330ns (0.1%) settling time make these devices excellent components in fast, accurate data acquisition and pulse amplification designs. 12MHz small signal bandwidth and 500kHz power bandwidth make these devices well suited to R.F. and video applications. With 2mV typical offset voltage plus offset trim capability and 10nA offset current, HA-2500/2502/2505 are particularly useful components in signal conditioning designs.

Applications

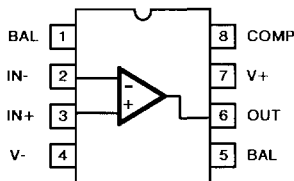
- Data Acquisition Systems
- R.F. Amplifiers
- Video Amplifiers
- Signal Generators
- Pulse Amplification

The gain and offset voltage figures of the HA-2500 series are optimized by internal component value changes while the similar design of the HA-2510 series is maximized for slew rate.

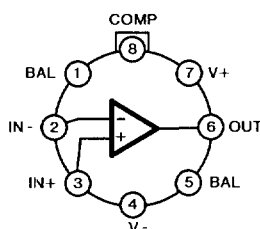
The HA-2500 and HA-2502 have guaranteed operation from -55°C to $+125^{\circ}\text{C}$ and are available in hermetic metal can and ceramic miniDIP packages. Both are offered as a /883 military grade part with the HA-2502 also available in LCC package. The HA-2505 has guaranteed operation from 0°C to $+75^{\circ}\text{C}$ and is available in plastic and ceramic miniDIP and metal can packages. Mil-Std-883 product and data sheets are available upon request.

Pinouts

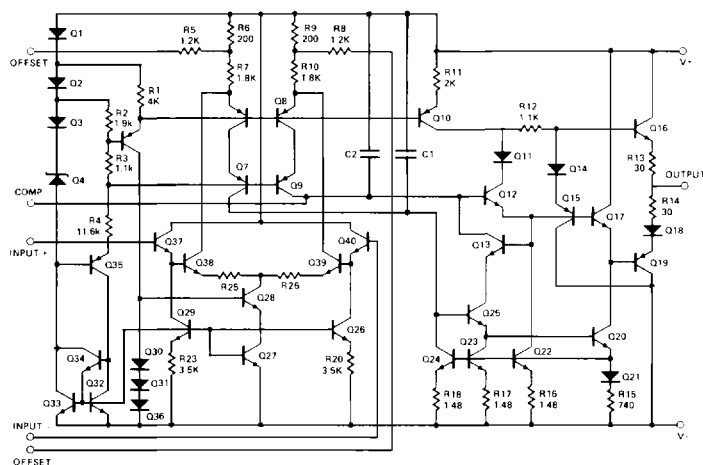
HA7-2500/02/02 (CERAMIC MINI-DIP)
HA3-2505 (PLASTIC MINI-DIP)
TOP VIEW



HA2-2500/02/05 (TO-99 METAL CAN)
TOP VIEW



Schematic



Specifications HA-2500/2502/2505

Absolute Maximum Ratings (Note 6)

Voltage Between V+ and V- Terminals 40.0V
 Differential Input Voltage $\pm 15.0V$
 Peak Output Current 50mA
 Internal Power Dissipation 300mW
 Lead Solder Temperature (10 Seconds) +275°C

Operating Temperature Range

HA-2510/2512 $-55^{\circ}C \leq T_A \leq +125^{\circ}C$
 HA-2515 $0^{\circ}C \leq T_A \leq +75^{\circ}C$
 Storage Temperature Range $-65^{\circ}C \leq T_A \leq +150^{\circ}C$
 Maximum Junction Temperature +175°C

Electrical Specifications V+ = +15V D.C., V- = -15V D.C.

PARAMETER	TEMP.	HA-2500 -55°C to +125°C			HA-2502 -55°C to +125°C			HA-2505 0°C to +75°C			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
INPUT CHARACTERISTICS											
Offset Voltage	+25°C Full		2	5 8		4	8 10		4	8 10	mV mV
Offset Voltage Average Drift	Full		20			20			20		µV/°C
Bias Current	+25°C Full		100	200 400		125	250 500		125	250 500	nA nA
Offset Current	+25°C Full		10	25 50		20	50 100		20	50 100	nA nA
Input Resistance (Note 10)	+25°C	25	50		20	50		20	50		MΩ
Common Mode Range	Full	± 10.0			± 10.0			± 10.0			V
TRANSFER CHARACTERISTICS											
Large Signal Voltage Gain (Note 1, 4)	+25°C Full	20K 15K	30K		15K 10K	25K		15K 10K	25K		V/V V/V
Common Mode Rejection Ratio (Note 2)	Full	80	90		74	90		74	90		dB
Gain Bandwidth Product (Note 3)	+25°C		12			12			12		MHz
OUTPUT CHARACTERISTICS											
Output Voltage Swing (Note 1)	Full	± 10.0	± 12.0		± 10.0	± 12.0		± 10.0	± 12.0		V
Output Current (Note 4)	+25°C	± 10	± 20		± 10	± 20		± 10	± 20		mA
Full Power Bandwidth (Notes 4,11)	+25°C	350	500		300	500		300	500		KHz
TRANSIENT RESPONSE											
Rise Time (Notes 1, 5, 7 & 8)	+25°C		25	50		25	50		25	50	ns
Overshoot (Notes 1, 5, 7 & 8)	+25°C		25	40		25	50		25	50	%
Slew Rate (Notes 1, 5, 8 & 12)	+25°C	± 25	± 30		± 20	± 30		± 20	± 30		V/µs
Settling Time to 0.1% (Notes 1, 5, 8 & 12)	+25°C		0.33			0.33			0.33		µs
POWER SUPPLY CHARACTERISTICS											
Supply Current	+25°C		4	6		4	6		4	6	mA
Power Supply Rejection Ratio (Note 9)	Full	80	90		74	90		74	90		dB

NOTES

- 1 $R_L = 2K\Omega$
- 2 $V_{CM} = \pm 10V$
- 3 $A_V > 10$
- 4 $V_O = \pm 10.0V$
- 5 $C_L = 50pF$

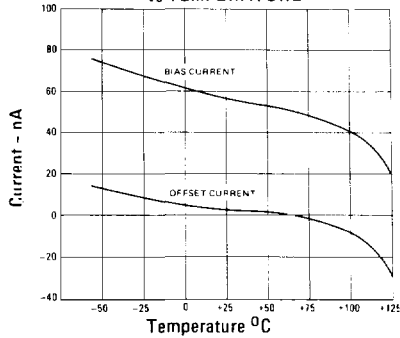
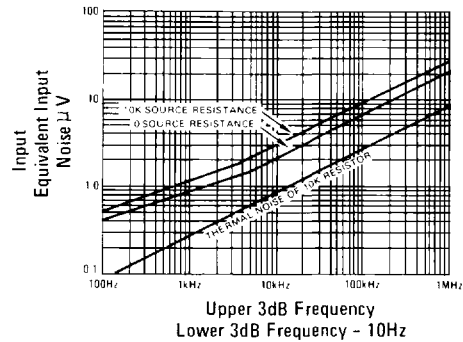
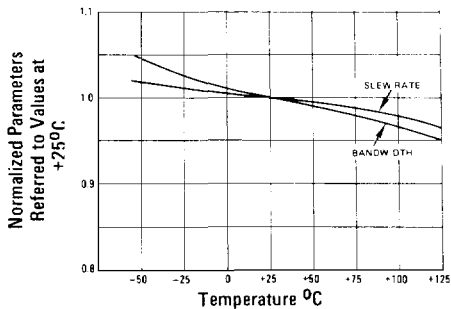
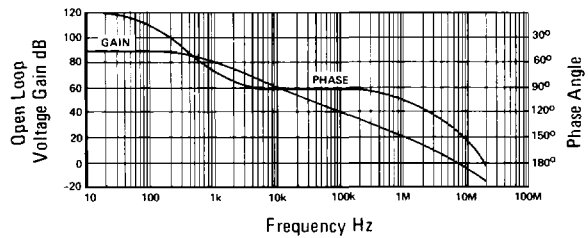
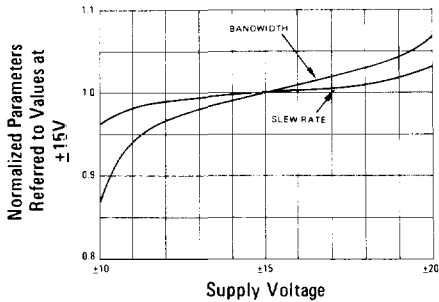
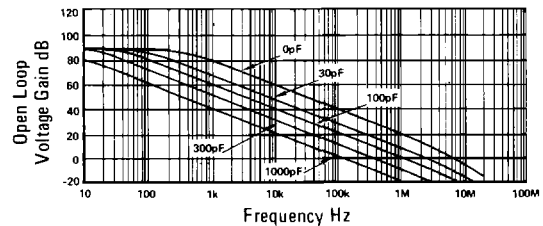
- 6 Absolute Maximum Ratings are limiting values, applied individually, beyond which the serviceability of the circuit may be impaired
- 7 $V_O = \pm 200mV$
- 8 See Transient Response Test Circuits and Waveforms

- 9 $\Delta V = \pm 5.0V$

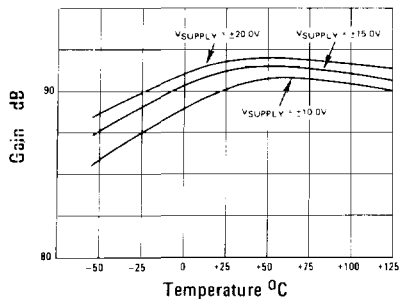
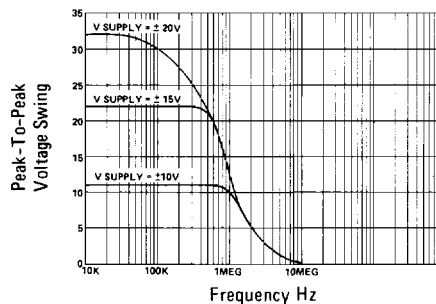
- 10 This parameter value is based on design calculations

- 11 Full Power Bandwidth guaranteed based on slew rate measurement using:
 $FPBW = S.R. / 2 \cdot V_{peak}$

- 12 $V_{OUT} = \pm 5V$

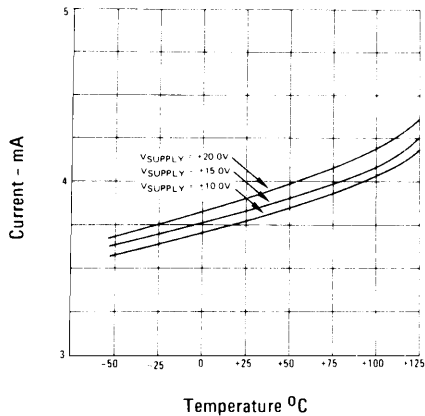
Performance Curves $V_+ = +15\text{VDC}$, $V_- = -15\text{VDC}$, $T_A = +25^\circ\text{C}$, Unless Otherwise Stated**INPUT BIAS AND OFFSET CURRENT
vs TEMPERATURE****EQUIVALENT INPUT NOISE
vs BANDWIDTH****NORMALIZED AC PARAMETERS
vs TEMPERATURE****OPEN-LOOP FREQUENCY AND PHASE RESPONSE****NORMALIZED AC PARAMETERS
vs SUPPLY VOLTAGE AT +25°C****OPEN LOOP FREQUENCY RESPONSE FOR
VARIOUS VALUES OF CAPACITORS FROM
COMPENSATION PIN TO GROUND**

NOTE: External compensation components are not required for stability, but may be added to reduce bandwidth if desired.

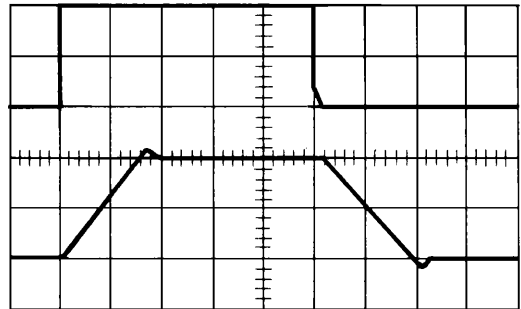
**OPEN LOOP VOLTAGE GAIN
vs TEMPERATURE****OUTPUT VOLTAGE SWING
vs FREQUENCY AT +25°C**

Typical Performance Curves (Continued)

POWER SUPPLY CURRENT vs TEMPERATURE



VOLTAGE FOLLOWER PULSE RESPONSE

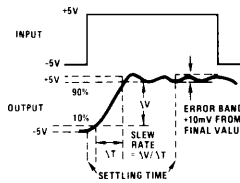


$R_L = 2K\Omega$, $C_L = 50pF$
 Upper Trace: Input
 Lower Trace: Output

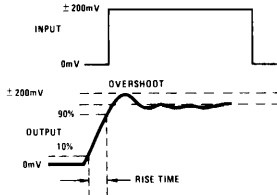
Vertical = 5V/Div.
 Horizontal = 200ns/Div.
 $T_A = +25^\circ C$, $V_S = \pm 15.0V$

Test Circuits

SLEW RATE AND SETTLING TIME

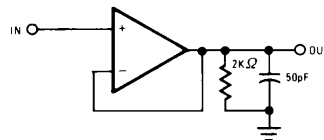


TRANSIENT RESPONSE

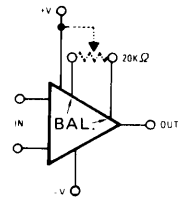


NOTE: Measurement on both positive and negative transitions from 0V to +200mV and 0V to -200mV at the output.

SLEW RATE AND TRANSIENT RESPONSE

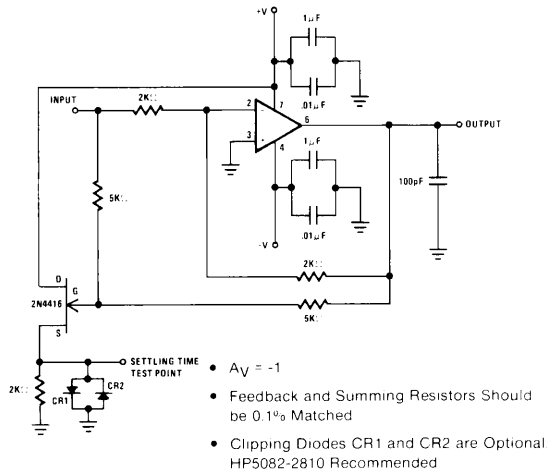


SUGGESTED VOS ADJUSTMENT



Tested Offset Adjustment Range is $|V_{OS} + 1mV|$ minimum referred to output. Typical ranges is $\pm 6mV$ with $R_T = 20k\Omega$.

Settling Time Circuit



Die Characteristics

Transistor Count	40	
Die Dimensions	57 x 65 x 19 mils	
Substrate Potential	Unbiased	
Process	Bipolar-DI	
Thermal Constants (°C/W)	θ_{ja}	θ_{jc}
HA2- Metal Can (-2, -5, -7)	202	56
HA2- Metal Can (-8, /883)	168	52
HA3- Plastic Mini-DIP (-5)	84	34
HA4- Ceramic LCC (/883)	97	35
HA7- Ceramic Mini-DIP (-8, /883)	138	63
HA7- Ceramic Mini-DIP (-2, -5, -7)	204	112